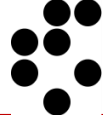


New TPA-TCT system at Jozef Stefan Institute (JSI)

38th RD50 Workshop, online, 23. 06. 2021

Bojan Hiti, F9, Jožef Stefan Institute (JSI)



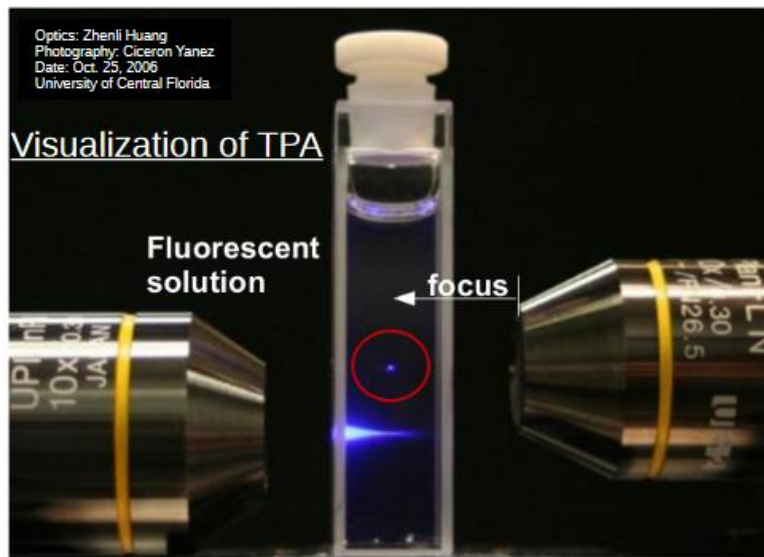
Reminder: Two Photon Absorption TCT



Two Photon Absorption - TCT



Single Photon Absorption
Continuous energy deposition along beam direction



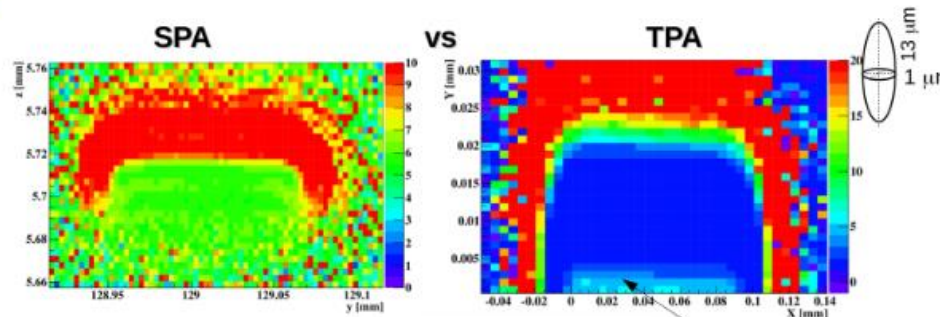
Two Photon Absorption
Absorption only at focal point

M. Wiehe,
35th RD50 Workshop

Confine photons in **time (femto-second laser)** and in **space (microfocusing)** for Two Photon Absorption

- 12th of March 2013, first TPA-TCT measurement at SGIker facility of UPV, Bilbao
- November 2014: Presentation of TPA-TCT at 25th CERN RD50 workshop
- 2013 – 2017: TPA-TCT measurements at UPV, Bilbao

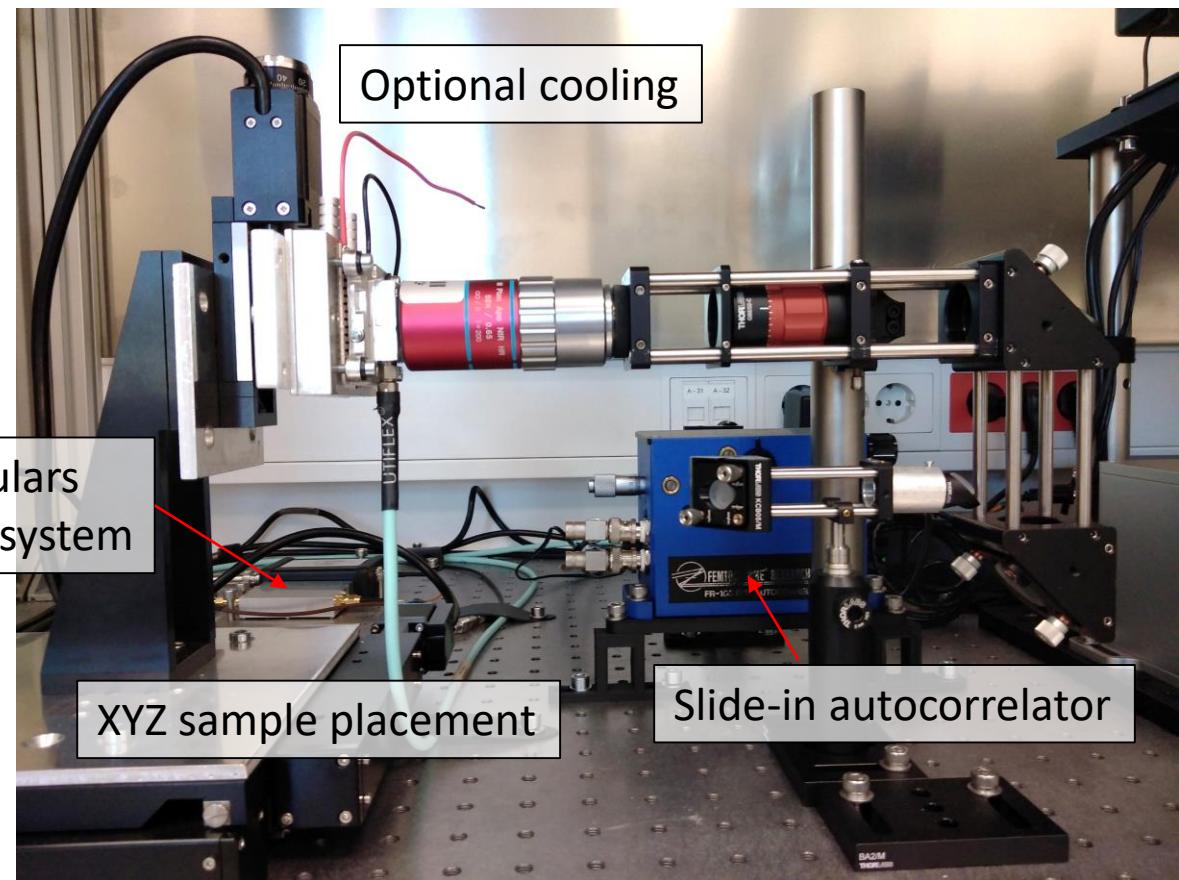
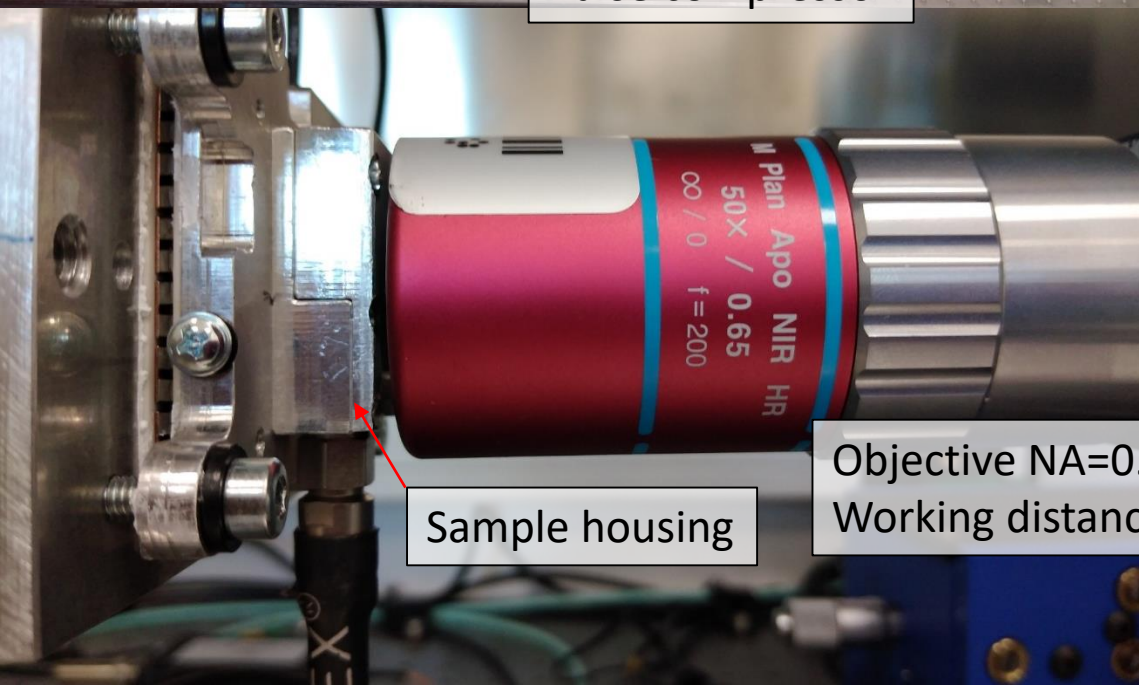
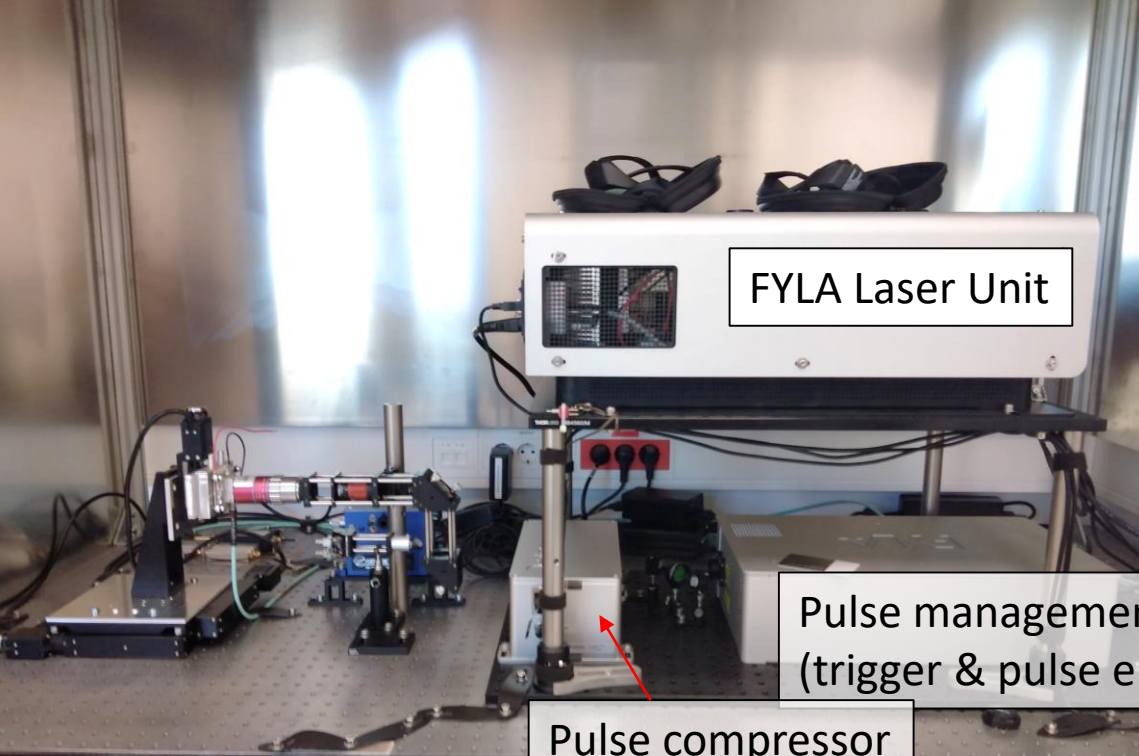
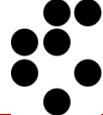
1) NIMA Vol 845, 11 February 2017, Pages 69-71
<https://doi.org/10.1016/j.nima.2016.05.070>
 2) Journal of Instrumentation, Volume 12, January 2017
<http://iopscience.iop.org/article/10.1088/1748-0221/12/01/C01038>

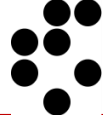


deep n-well in HVCMOS
Not resolved in SPA-TCT



- New TPA-TCT system built at JSI
- Based on FYLA LFC 1500X fs laser ($\lambda=1550$ nm)
- Readout electronics and DAQ based on standard Particulars TCT
- First TPA signals observed in May 2021



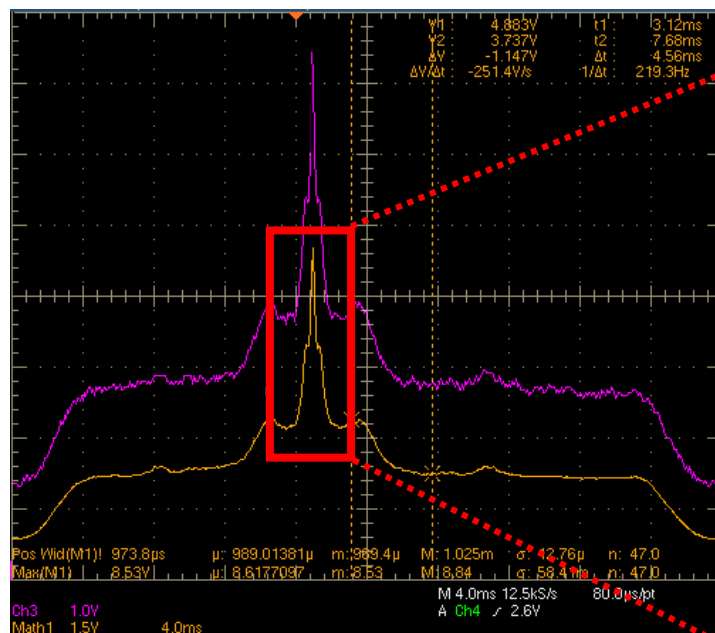


TPA laser pulse: Time domain

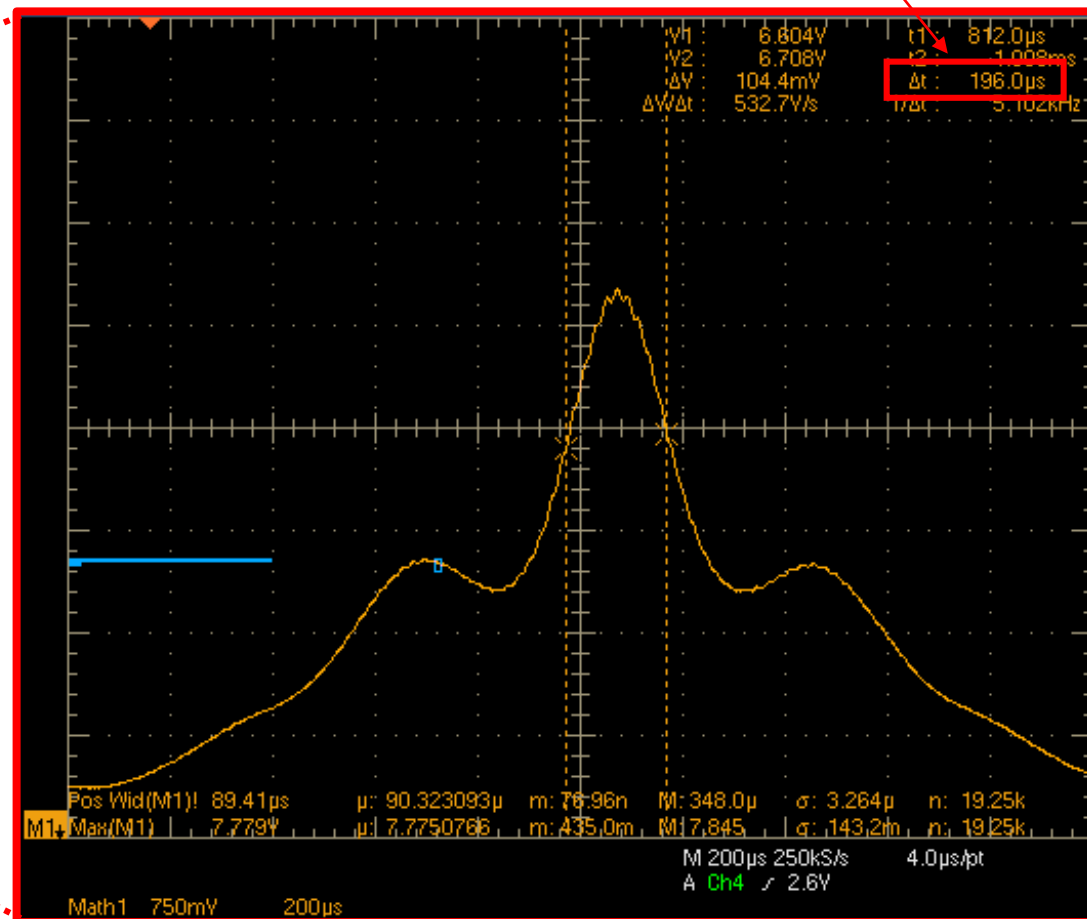
- Measurement of laser pulse duration with an autocorrelator

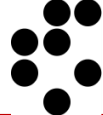
Pulse width (FWHM)
 $0.196 \text{ ms} \times 1600 \text{ fs/ms} = 310 \text{ fs}$

Autocorrelator output



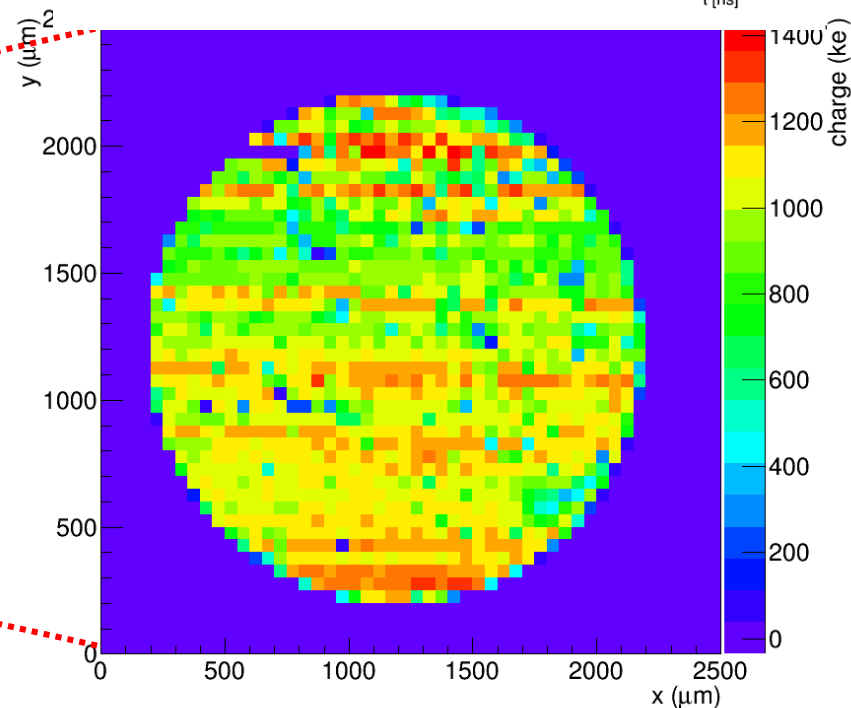
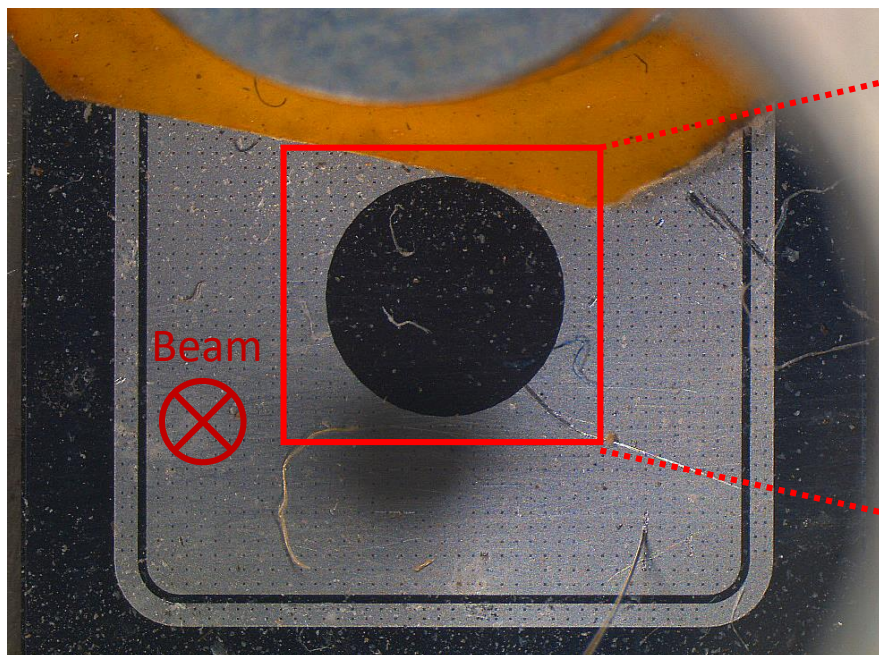
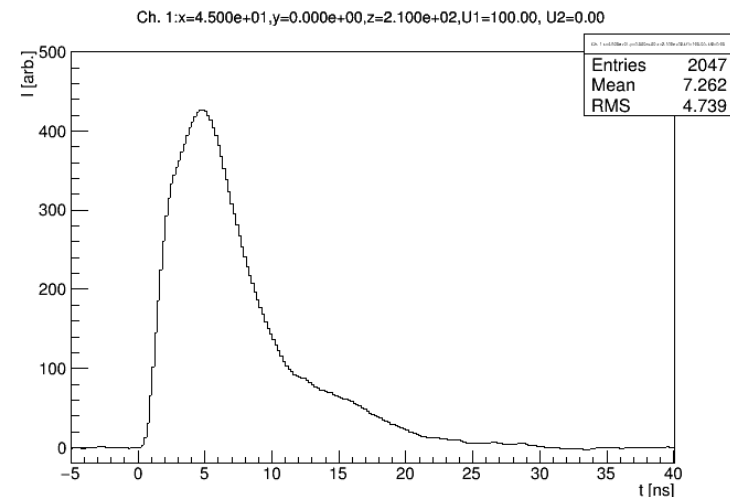
Pulse duration $\approx 300 \text{ fs}$

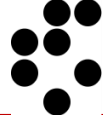




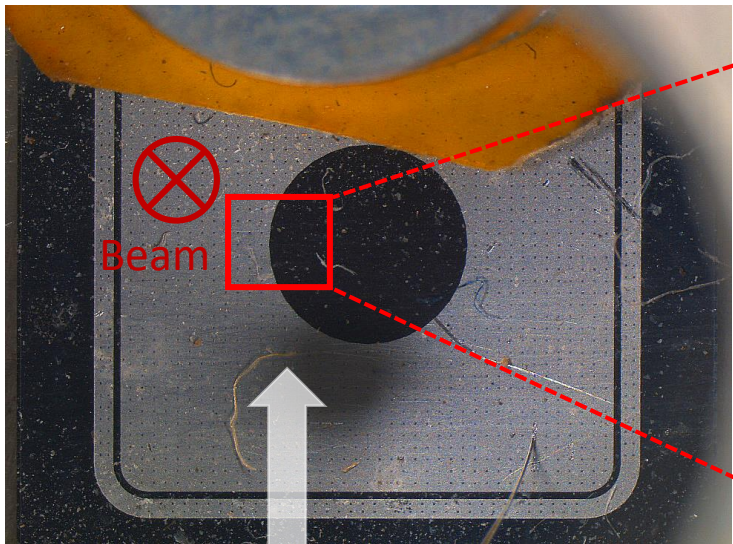
First TPA-TCT measurements

- Sample:
 - 6 x 6 mm p-in-n pad diode, metalization opening 2 mm
 - Thickness 300 μm , 10 $\text{k}\Omega\cdot\text{cm}$, unirradiated
- Charge = time integral (50 ns) of TCT-pulse
- Amplifier output calibrated with Am^{241} alpha source (5.4 MeV)

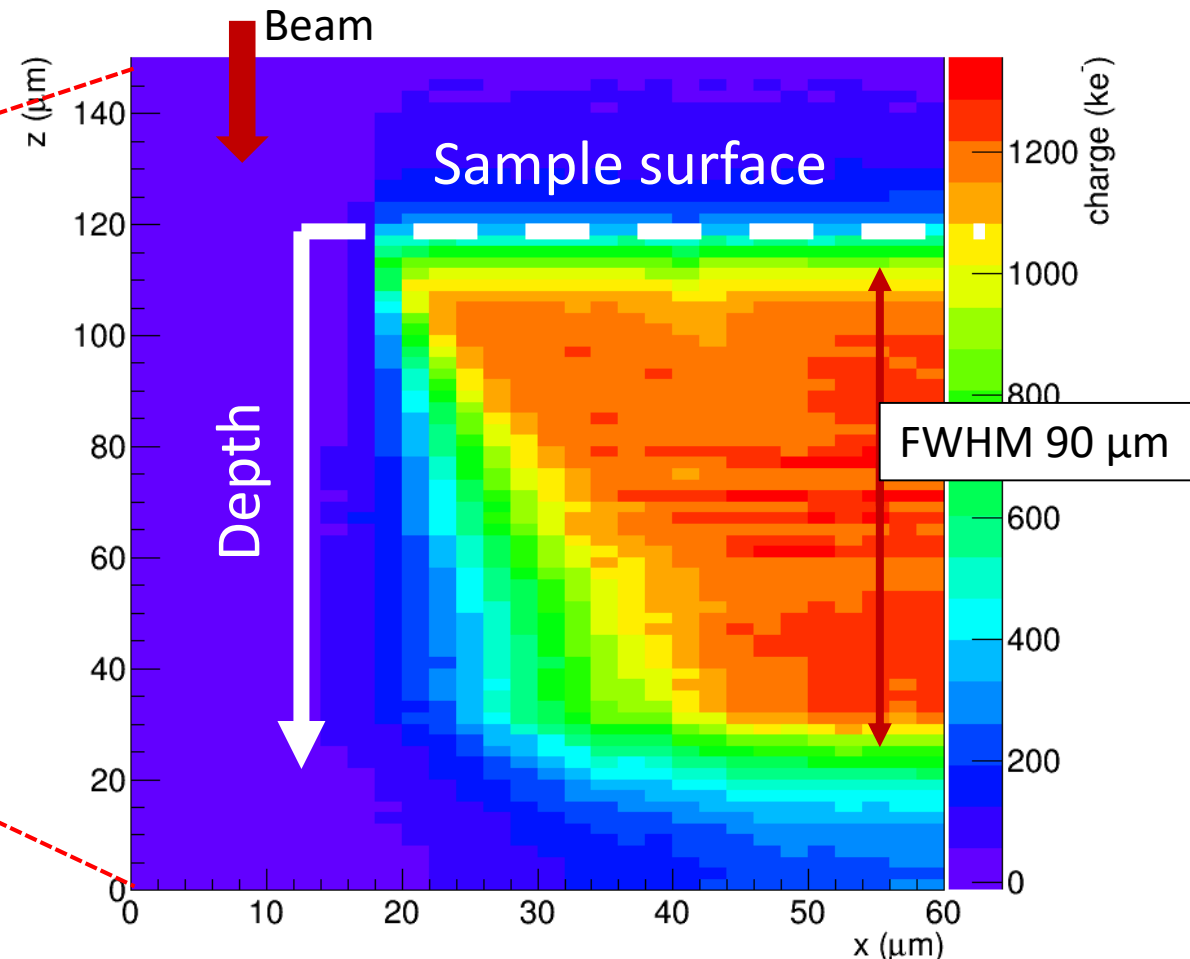




First TPA-TCT measurements

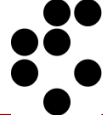


Direction of projection



z-dimension not yet corrected for light refraction in silicon
→ Analysis ongoing

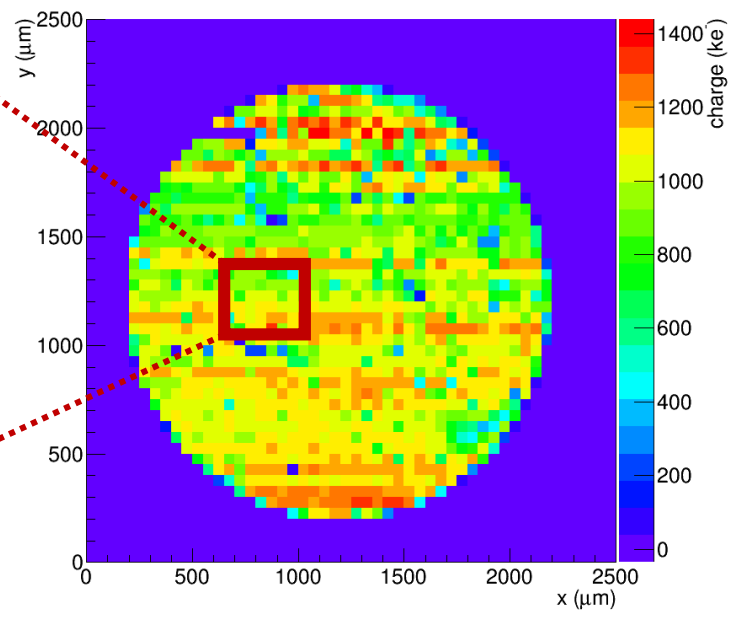
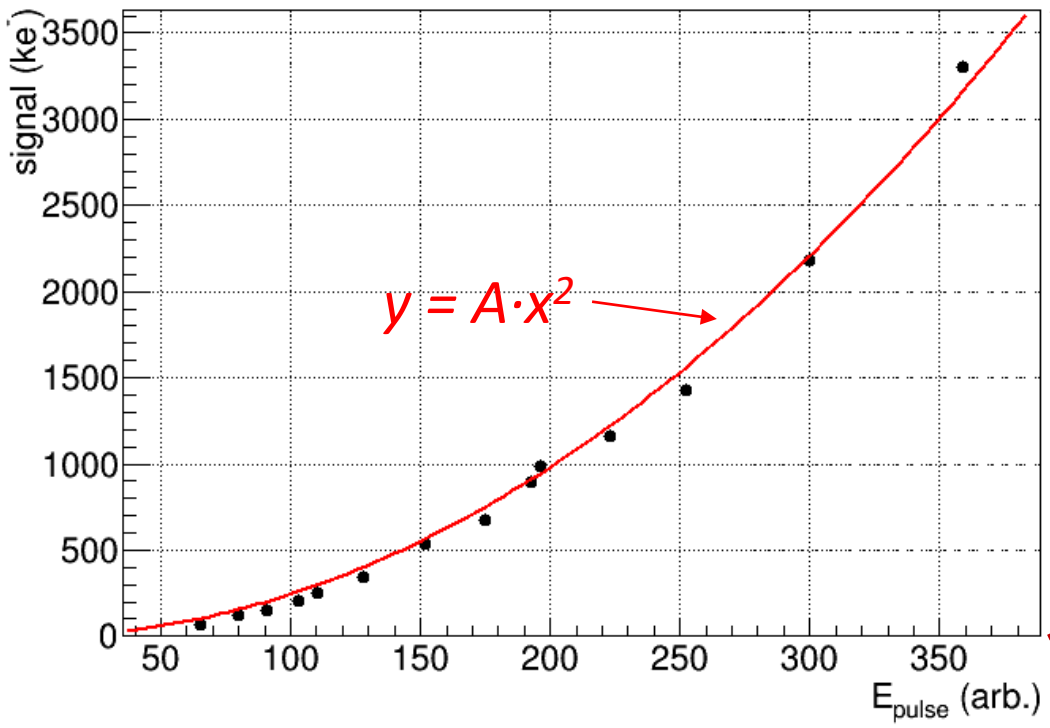
$FWHM \times n_{Si} = 90 \mu m \times 3.4 = 306 \mu m$
→ compatible with device thickness



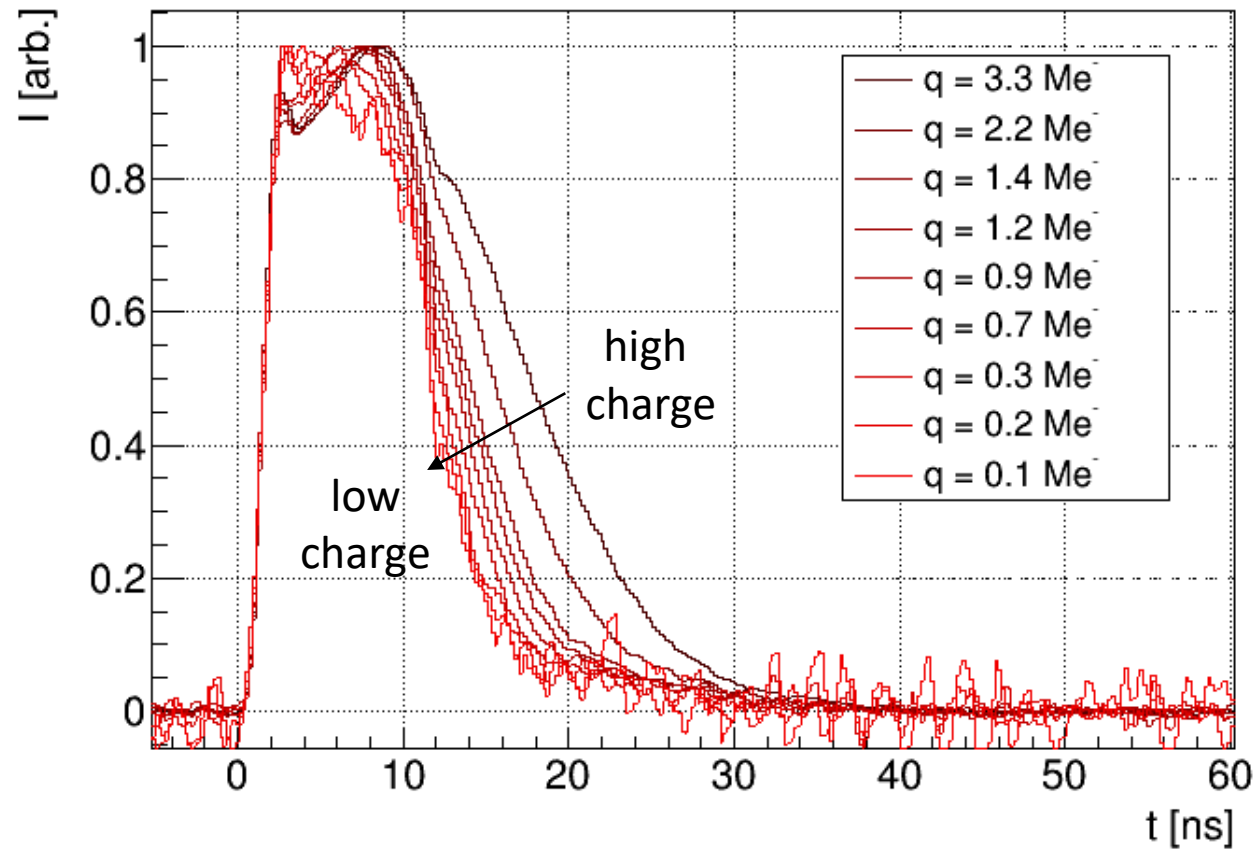
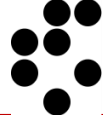
Dependence of signal size on pulse energy

- Varying laser power at fixed point in the sample

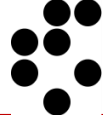
- Charge carrier generation equation:
$$\frac{dN(r, z)}{dt} = \underbrace{\frac{\alpha I(r, z)}{\hbar\omega}}_{\text{SPA}} + \underbrace{\frac{\beta_2 I^2(r, z)}{2\hbar\omega}}_{\text{TPA}}$$



Signal size $\propto (\text{Irradiance})^2$ – Proof of TPA

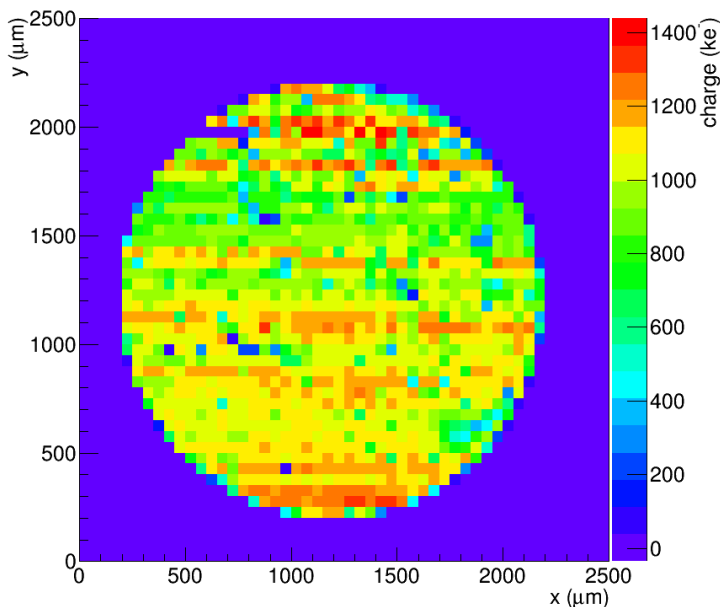
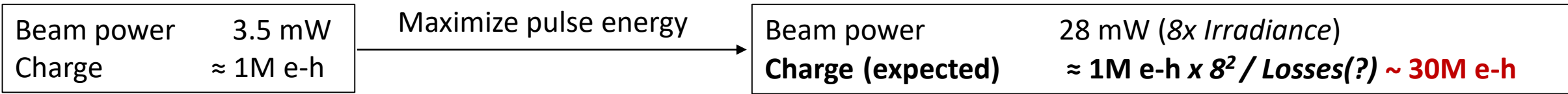


- TCT signals at different pulse energies normalized to the same height
- Onset of plasma effect at $> 2 \text{ Me}^-$ injected charge (E-field screening \rightarrow elongated pulse)



SEU studies potential

- LGAD mortality studies require charge of the order of 30M e-h pairs
 - Can it be done with TPA?
- Maximized signals cannot be measured directly (amplifier saturation)
- Beam intensity measurement with power meter (before entering objective) – (PM100D + S401C), pulse rate 4 MHz
- Pulse energy is selected with adjustable neutral density filter → should not change pulse shape



Maximal signals in the range of 30M e-h pairs seem to be achievable



- New TPA-TCT system under commissioning at JSI
- First measurements demonstrated operation in TPA mode
- Beam characterization ongoing
- In future tests with irradiated sample
- Plan to investigate SEU test capabilities